







SN54AHC14, SN74AHC14

SCLS238P - OCTOBER 1995 - REVISED FEBRUARY 2024

SNx4AHC14 Hex Schmitt-Trigger Inverters

1 Features

- · ESD protection exceeds JESD 22:
 - 2000V Human-Body Model (A114-A)
 - 200V Machine Model (A115-A)
 - 1000V Charged-Device Model (C101)
- Operating range: 2V to 5.5V
- ±8mA output drive at 5V
- Schmitt-Trigger inputs enable input noise resistance
- Low power consumption: 20µA maximum I_{CC}
- Latch-up performance exceeds 250mA per JESD 17

2 Applications

- **UPS**
- White goods
- Computer peripherals
- Printers
- AC servo drives
- **Desktop computers**

3 Description

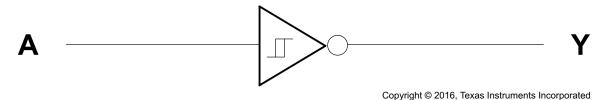
The SNx4AHC14 devices contain six independent inverters. These devices perform the boolean function $Y = \overline{A}$

Each circuit functions as an independent inverter, but, because of the Schmitt-Trigger action, the inverters have different input threshold levels for positive-going (V_{T+}) and negative-going (V_{T-}) signals.

Device Information

PART NUMBER	RATING	PACKAGE ⁽¹⁾
		J (CDIP, 14)
SN54AHC14	Military	W (CFP, 14)
31134AI 10 14	ivilital y	FK (LCCC, 20)
		BQA (WQFN, 14)
		D (SOIC, 14)
		DB (SSOP, 14)
		N (PDIP, 14)
0.0174.011.04.4	0	NS (SO, 14)
SN74AHC14	Commercial	PW (TSSOP, 14)
		DGV (TVSOP, 14)
		RGY (VQFN, 14)
		BQA (WQFN, 14)

For all available packages, see the orderable addendum at the end of the data sheet.



Logic Diagram (Positive Logic)



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4 Pin Configuration and Functions

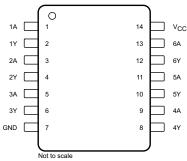


Figure 4-1. D, DB, DGV, J, N, NS, PW, or W Package, 14-Pin SOIC, SSOP, TVSOP, CDIP, PDIP, SO, TSSOP, or CFP (Top View)

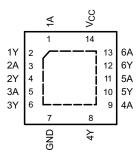


Figure 4-2. RGY or BQA Package, 14-Pin VQFN or WQFN (Top View)

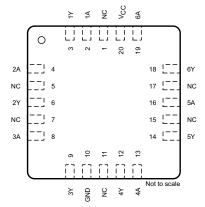


Figure 4-3. FK Package, 20-Pin LCCC (Top View)

Table 4-1. Pin Functions

	PIN			
NAME	SOIC, SSOP, TVSOP, CDIP, PDIP, SO, TSSOP, CFP, VQFN	LCCC	TYPE ⁽¹⁾	DESCRIPTION
1A	1	2	I	Channel 1 Input
1Y	2	3	0	Channel 1 Output
2A	3	4	I	Channel 2 Input
2Y	4	6	0	Channel 2 Output
ЗА	5	8	I	Channel 3 Input
3Y	6	9	0	Channel 3 Output
4A	9	13	ı	Channel 4 Input
4Y	8	12	0	Channel 4 Output
5A	11	16	I	Channel 5 Input
5Y	10	14	0	Channel 5 Output
6A	13	19	I	Channel 6 Input
6Y	12	18	0	Channel 6 Output
GND	7	10	_	Ground
NC	_	1, 5, 7, 11, 15, 17	_	No internal connection
V _{CC}	14	20	_	Power supply

(1) I = input, O = output



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		-0.5	7	V
V _I (2)	Input voltage		-0.5	7	V
V _O ⁽²⁾	Output voltage		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		±25	mA
	Continuous current through V _{CC} or GND			±50	mA
TJ	Virtual operating junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2	5.5	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
I _{OH} High-level output current	V _{CC} = 2 V		-50	μA	
	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	mA
		$V_{CC} = 5 V \pm 0.5 V$		-8	
		V _{CC} = 2 V		50	μA
I _{OL}	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	- mA
		V _{CC} = 5 V ± 0.5 V		8	
т	Operating free-air temperature	SN54AHC14	– 55	125	°C
T _A	Operating free-all temperature	SN74AHC14	-40	125	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See TI application report, *Implications of Slow or Floating CMOS Inputs* (SCBA004).

Product Folder Links: SN54AHC14 SN74AHC14

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



5.4 Thermal Information

		SN74AHC14								
THE	RMAL METRIC ⁽¹⁾	D (SOIC)	DB (SSOP)	DGV (TVSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	RGY (VQFN)	BQA (WQFN)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	124.5	137.8	141.9	61.9	94.7	147.7	87.1	88.3	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	78.8	90	61.1	49.5	52.5	77.4	92.6	90.9	°C/W
R _{θJB}	Junction-to-board thermal resistance	81	98.3	71.3	41.7	53.4	90.9	62.5	56.8	°C/W
ΨЈТ	Junction-to-top characterization parameter	37	42.7	9.7	34.7	21.3	27.2	22.8	9.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	80.6	97	70.6	41.7	53.1	90.2	61.7	56.7	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	N/A	45.1	33.4	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TES.	T CONDITIONS	MIN	TYP MA	X UNIT	
			V _{CC} = 3 V	1.2	2	.2	
V _{T+}	Positive-going input threshold voltage		V _{CC} = 4.5 V	1.75	3.	15 V	
	an sensia veitags		V _{CC} = 5.5 V	2.15	3.	35	
			V _{CC} = 3 V	0.9	1	.9	
V _{T-}	Negative-going input threshold voltage		V _{CC} = 4.5 V	1.35	2.	75 V	
	uneshold voltage		V _{CC} = 5.5 V	1.65	3.	35	
	ΔV_{T} Hysteresis ($V_{T+} - V_{T-}$)		V _{CC} = 3 V	0.3	1	.2	
ΔV_T			V _{CC} = 4.5 V	0.4	1	.4 V	
			V _{CC} = 5.5 V	0.5	1	.6	
			V _{CC} = 2 V	1.9	2		
		I _{OH} = -50 μA	V _{CC} = 3 V	2.9	3		
			V _{CC} = 4.5 V	4.4	4.5		
V _{OH}	V _{OH}	1 - 4 - 2 \	T _A = 25°C	2.58		V	
		$I_{OH} = -4 \text{ mA}, V_{CC} = 3 \text{ V}$	SNx4AHC14	2.48			
			T _A = 25°C	3.94			
		$I_{OL} = -8 \text{ mA}, V_{CC} = 4.5 \text{ V}$		SNx4AHC14	3.8		



5.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CON	MIN TYP	MAX	UNIT		
			V _{CC} = 2 V			0.1	
		I _{OH} = 50 μA	V _{CC} = 3 V			0.1	
			V _{CC} = 4.5 V			0.1	
			T _A = 25°C			0.36	
			SN54AHC14			0.5	
.,		I_{OH} = 4 mA, V_{CC} = 3 V	SN74AHC14	T _A = -40°C to 85°C		0.44	.,
V _{OL}			SIV/4AFIC 14	T _A = -40°C to 125°C		0.5	V
			T _A = 25°C			0.36	
			SN54AHC14			0.5	
		I _{OL} = 8 mA, V _{CC} = 4.5 V		T _A = -40°C to 85°C		0.44	
		SN/4P	SN74AHC14	T _A = -40°C to 125°C		0.5	ı
		V _I = 5.5 V or GND,	T _A = 25°C			±0.1	
l _l		V _{CC} = 0 V to 5.5 V	SNx4AHC14			±1 ⁽¹⁾	μA
1		$V_I = V_{CC}$ or GND, $I_O = 0$,	T _A = 25°C			1	μA
I _{CC}		V _{CC} = 5.5 V	SNx4AHC14			20	μΑ
Cı		$V_I = V_{CC}$ or GND, $V_{CC} = 5 \text{ V}$	T _A = 25°C		2	10	pF
<u></u>		VI = VCC OF GIVE, VCC = 3 V	SN74AHC14			10	рі
C_{pd}	Power dissipation capacitance	No load, f = 1 MHz, V _{CC} = 5 V			9		pF
NOISE(2)						
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}	V _{CC} = 5 V, C _L = 50 pF, T _A = 25°C			0.8		V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}	V _{CC} = 5 V, C _L = 50 pF, T _A = 25°C			-0.4		V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	V _{CC} = 5 V, C _L = 50 pF, T _A = 25°C			4.6		V
V _{IH(D)}	High-level dynamic input voltage	V _{CC} = 5 V, C _L = 50 pF, T _A = 25°C			3.5		V
V _{IL(D)}	Low-level dynamic input voltage	V _{CC} = 5 V, C _L = 50 pF, T _A = 25°C				1.5	V

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested at V_{CC} = 0 V.

⁽²⁾ Characteristics are for surface-mount packages only.



5.6 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

 $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ and over operating free-air temperature range (unless otherwise noted; see *Parameter Measurement Information*)

PARAMETER	TEST CONDITIONS		MIN	TYP MAX	UNIT
		T _A = 25°C	8.3(1)	12.8(1)	
t _{PLH}	From A (input) to Y (output), C _L = 15 pF	SN54AHC14	1 ⁽¹⁾	15 ⁽¹⁾	ns
		SN74AHC14	1	16	
t _{PHL}		T _A = 25°C	8.3(1)	12.8(1)	
	From A (input) to Y (output), C _L = 15 pF	SN54AHC14	1 ⁽¹⁾	15 ⁽¹⁾	ns
		SN74AHC14	1	16	
		T _A = 25°C	10.8	16.3	ns
t _{PLH}	From A (input) to Y (output), C _L = 50 pF	SN54AHC14	1	18.5	
		SN74AHC14	1	19.5	
t _{PHL}		T _A = 25°C	10.8	16.3	
	From A (input) to Y (output), C _L = 50 pF	SN54AHC14	1	18.5	ns
		SN74AHC14	1	19.5	

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.

5.7 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

 V_{CC} = 5 V ± 0.5 V and over operating free-air temperature range (unless otherwise noted; see *Parameter Measurement Information*)

PARAMETER	TEST CONDITIO	NS	MIN	TYP MAX	UNIT
		T _A = 25°C	5.5 ⁽¹⁾	8.6(1)	
t _{PLH}	From A (input) to Y (output), C _L = 15 pF	SN54AHC14	1(1)	10 ⁽¹⁾	ns
		SN74AHC14	1	10	
t _{РНL}		T _A = 25°C	5.5 ⁽¹⁾	8.6(1)	
	From A (input) to Y (output), C _L = 15 pF	SN54AHC14	1 ⁽¹⁾	10 ⁽¹⁾	ns
		SN74AHC14	1	10	
		T _A = 25°C	7	10.6	
t _{PLH}	From A (input) to Y (output), C _L = 50 pF	SNx4AHC14	1	12	ns
t _{PHL}	From A (input) to Y (output), C _L = 50 pF	T _A = 25°C	7	10.6	no
		SNx4AHC14	1	12	ns

5.8 Typical Characteristics

C_L = 50 pF (unless otherwise noted)

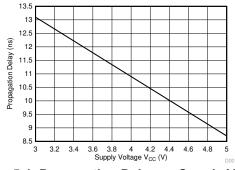


Figure 5-1. Propagation Delay vs Supply Voltage



6 Parameter Measurement Information

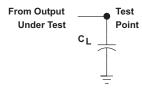


Figure 6-1. Load Circuit For Totem-Pole Outputs

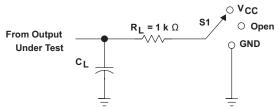


Figure 6-2. Load Circuit For 3-State and Open-Drain Outputs

۷он

50% V _{CC}

Table 6-1. Measurement Information

TEST	S1
t _{PLH} , t _{PHL}	Open
t _{PLZ} , t _{PZL}	V _{CC}
t _{PHZ} , t _{PZH}	GND
Open drain	V _{CC}

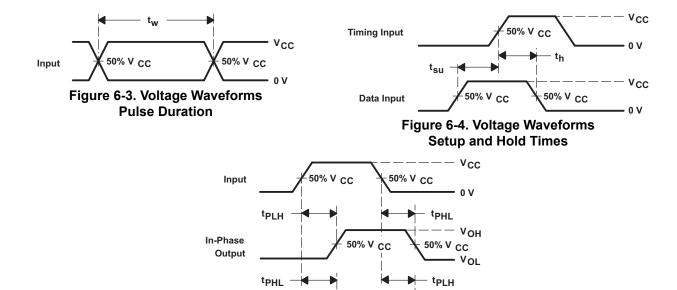


Figure 6-5. Voltage Waveforms Propagation Delay Times Inverting and Noninverting Outputs

50% V _{CC}

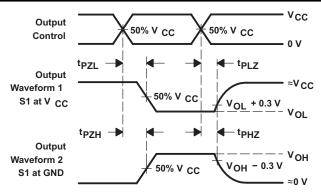
Out-of-Phase

Output

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- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , $t_r \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 6-6. Voltage Waveforms Enable and Disable Times Low- and High-Level Enabling



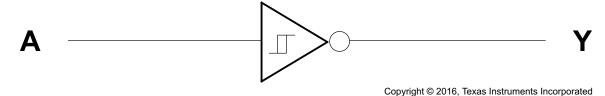
7 Detailed Description

7.1 Overview

The SNx4AHC14 Schmitt-Trigger devices contain six independent inverters. They perform the Boolean function $Y = \overline{A}$ in positive logic.

Schmitt-Trigger inputs are designed to provide a minimum separation between positive and negative switching thresholds. This allows for noisy or slow inputs that would cause problems such as oscillation or excessive current draw with normal CMOS inputs.

7.2 Functional Block Diagram



7.3 Feature Description

The wide operating range of the device allows it to be used in a variety of systems that use different logic levels. The outpus can drive up to 10 LSTTL loads each. The balanced drive outputs can source or sink 8 mA at 5-V V_{CC} .

7.4 Device Functional Modes

Table 7-1 lists the functional modes of the SNx4AHC14.

Table 7-1. Function Table

INPUT A	OUTPUT Y
Н	L
L	Н

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8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The SN74AHC14 device is a Schmitt-Trigger input CMOS device that can be used for a multitude of inverting buffer type functions. The application shown here takes advantage of the Schmitt-Trigger inputs to produce a delay for a logic input.

8.2 Typical Application

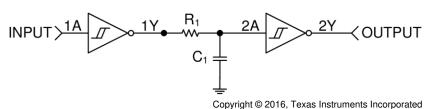


Figure 8-1. Simplified Application Schematic

8.2.1 Design Requirements

This device uses CMOS technology. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. Parallel output drive can create fast edges into light loads so consider routing and load conditions to prevent ringing.

8.2.2 Detailed Design Procedure

This circuit is designed around an RC network that produces a slow input to the second inverter. The RC time constant, T, is calculated from: T = RC.

The delay time for this circuit is from $t_{delay(min)} = -ln |1 - V_{T+(min)} / V_{CC}| \tau$ to $t_{delay(max)} = -ln |1 - V_{T+(max)} / V_{CC}| \tau$. It must be noted that the delay is consistent for each device, but because the switching threshold is only ensured between the minimum and maximum value, the output pulse length varies between devices. These values must be calculated by using the minimum and maximum V_{T+} values in the *Electrical Characteristics*.

The resistor value must be chosen such that the maximum current to and from the SN74AHC14 is 8 mA at 5-V V_{CC} .

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8.2.3 Application Curve

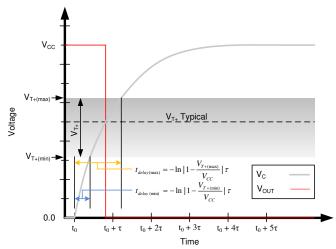


Figure 8-2. Ideal Capacitor Voltage and Output Voltage With Positive Switching Threshold

8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. The V_{CC} terminal must have a good bypass capacitor to prevent power disturbance. TI recommends using a 0.1- μ F capacitor on the V_{CC} terminal, and must be placed as close as possible to the pin for best results.

8.4 Layout

8.4.1 Layout Guidelines

When using multiple bit logic devices, inputs must never float. In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only three of the four buffer gates are used. Such inputs must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally they are tied to GND or V_{CC} , whichever makes more sense or is more convenient. Floating outputs are generally acceptable, unless the part is a transceiver.

8.4.2 Layout Example

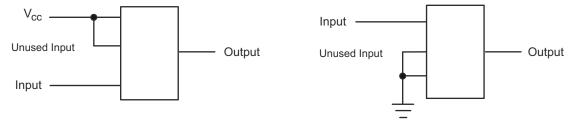


Figure 8-3. Layout Diagram



9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

Texas Instruments, Implications of Slow or Floating CMOS Inputs application report

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision O (October 2023) to Revision P (February 2024)

Page

 Updated RθJA values: DB = 112.4 to 137.8, RGY = 63.8 to 87.1; Updated DB and RGY packages for RθJC(top), RθJB, ΨJT, ΨJB, and RθJC(bot), all values in °C/W.......

Changes from Revision N (June 2023) to Revision O (October 2023)

Page

- Deleted machine model......4

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9680201Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9680201Q2A SNJ54AHC 14FK	Samples
5962-9680201QCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9680201QC A SNJ54AHC14J	Samples
5962-9680201QDA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9680201QD A SNJ54AHC14W	Samples
5962-9682001QCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9682001QC A SNJ54AHC08J	Samples
5962-9682001QDA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9682001QD A SNJ54AHC08W	Samples
SN74AHC14BQAR	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC14	Samples
SN74AHC14D	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 125	AHC14	
SN74AHC14DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA14	Samples
SN74AHC14DGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA14	Samples
SN74AHC14DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC14	Samples
SN74AHC14DRE4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC14	Samples
SN74AHC14DRG3	ACTIVE	SOIC	D	14	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	AHC14	Samples
SN74AHC14DRG4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC14	Samples
SN74AHC14N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHC14N	Samples
SN74AHC14NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC14	Samples
SN74AHC14PW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-40 to 125	HA14	

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC14PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	HA14	Samples
SN74AHC14PWRG3	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	HA14	Samples
SN74AHC14PWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA14	Samples
SN74AHC14RGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA14	Samples
SNJ54AHC08J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9682001QC A SNJ54AHC08J	Samples
SNJ54AHC08W	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9682001QD A SNJ54AHC08W	Samples
SNJ54AHC14FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9680201Q2A SNJ54AHC 14FK	Samples
SNJ54AHC14J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9680201QC A SNJ54AHC14J	Samples
SNJ54AHC14W	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9680201QD A SNJ54AHC14W	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

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(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54AHC14, SN74AHC14:

Catalog: SN74AHC14

Enhanced Product: SN74AHC14-EP, SN74AHC14-EP

Military: SN54AHC14

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

• Military - QML certified for Military and Defense Applications



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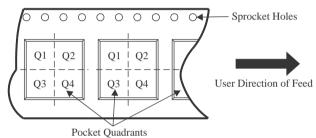
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC14BQAR	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1
SN74AHC14DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74AHC14DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74AHC14DGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74AHC14DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC14DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC14DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC14DRG3	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.1	8.0	16.0	Q1
SN74AHC14DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC14NSR	so	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74AHC14PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC14PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC14PWRG3	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC14PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC14PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC14RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC14BQAR	WQFN	BQA	14	3000	210.0	185.0	35.0
SN74AHC14DBR	SSOP	DB	14	2000	353.0	353.0	32.0
SN74AHC14DBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74AHC14DGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74AHC14DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74AHC14DR	SOIC	D	14	2500	353.0	353.0	32.0
SN74AHC14DR	SOIC	D	14	2500	353.0	353.0	32.0
SN74AHC14DRG3	SOIC	D	14	2500	364.0	364.0	27.0
SN74AHC14DRG4	SOIC	D	14	2500	353.0	353.0	32.0
SN74AHC14NSR	SO	NS	14	2000	356.0	356.0	35.0
SN74AHC14PWR	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74AHC14PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74AHC14PWRG3	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74AHC14PWRG4	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74AHC14PWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74AHC14RGYR	VQFN	RGY	14	3000	360.0	360.0	36.0

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9680201Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9680201QDA	W	CFP	14	25	506.98	26.16	6220	NA
5962-9682001QDA	W	CFP	14	25	506.98	26.16	6220	NA
SN74AHC14N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC14N	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54AHC08W	W	CFP	14	25	506.98	26.16	6220	NA
SNJ54AHC14FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54AHC14W	W	CFP	14	25	506.98	26.16	6220	NA



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



2.5 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com

PLASTIC QUAD FLAT PACK-NO LEAD



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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